Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:

Plastic

Overall Length:

Between 0.660 inches and 0.785 inches

Overall Height:

Between 0.140 inches and 0.180 inches

Overall Width:

Between 0.220 inches and 0.280 inches

Component Name And Quantity:

4 transistor

Mounting Method:

Press fit

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

60.0 collector to emitter voltage, dc all transistor and 60.0 collector to emitter reverse voltage all transistor and 40.0 collector to emitter

voltage/static/base open all transistor

Current Rating Per Characteristic:

1.50 amperes source cutoff current horsepower metric all transistor

Power Rating Per Characteristic:

750.0 milliwatts small-signal input power, common-collector preset all transistor

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

14 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0